

<b>L Number</b>	<b>Hits</b>	<b>Search Text</b>	<b>DB</b>	<b>Time stamp</b>
1	424	g11b005/235.ipc.	EPO; JPO; DERWENT	2003/01/08 12:58
2	3449	SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6)	EPO; JPO; DERWENT	2003/01/08 13:50
3	1	g11b005/235.ipc. and (SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6))	EPO; JPO; DERWENT	2003/01/08 13:00
4	157	g11b\$.ipc. and (SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6))	EPO; JPO; DERWENT	2003/01/08 13:01
5	30	SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6)	IBM_TDB	2003/01/08 13:39
6	9412	SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6)	USPAT; US-PGPUB	2003/01/08 13:20
7	35939	360/\$.ccls.	USPAT; US-PGPUB	2003/01/08 13:20
8	257	360/120.ccls.	USPAT; US-PGPUB	2003/01/08 13:20
9	3	(SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6)) and 360/120.ccls.	USPAT; US-PGPUB	2003/01/08 13:22
10	59	(SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6)) and 360/\$.ccls.	USPAT; US-PGPUB	2003/01/08 13:22
11	56	((SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6)) and 360/\$.ccls.) not ((SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6)) and 360/120.ccls.)	USPAT; US-PGPUB	2003/01/08 13:22
12	0	((gap or insulat\$5 or dielectric) adj2 (layer or film or coating)) WITH ((SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6)))	IBM_TDB	2003/01/08 13:41
13	1005	((gap or insulat\$5 or dielectric) adj2 (layer or film or coating)) WITH ((SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6)))	USPAT; US-PGPUB	2003/01/08 13:43
14	30307	magnetic adj2 (head or transduc\$5)	USPAT; US-PGPUB	2003/01/08 13:43
15	18	((gap or insulat\$5 or dielectric) adj2 (layer or film or coating)) WITH ((SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6))) and (magnetic adj2 (head or transduc\$5))	USPAT; US-PGPUB	2003/01/08 13:43
16	4773	(silicon near2 oxide near2 nitr\$6)	EPO; JPO; DERWENT	2003/01/08 13:51
17	144	g11b\$.ipc. and ( (silicon near2 oxide near2 nitr\$6))	EPO; JPO; DERWENT	2003/01/08 13:52
18	140	(g11b\$.ipc. and ( (silicon near2 oxide near2 nitr\$6))) not (g11b\$.ipc. and (SiON or (Si adj2 O adj2 N) or (silicon adj2 oxygen adj2 nitr\$6)))	EPO; JPO; DERWENT	2003/01/08 14:02
19	1613	silicon near2 (oxynitr\$6 or oxy adj2 nitr\$6)	EPO; JPO; DERWENT	2003/01/08 14:07
20	29	g11b\$.ipc. and (silicon near2 (oxynitr\$6 or oxy adj2 nitr\$6))	EPO; JPO; DERWENT	2003/01/08 14:04

<b>21</b>	<b>29</b>	<b>silicon near2 (oxynitr\$6 or oxy adj2 nitr\$6)</b>	<b>IBM_TDB</b>	<b>2003/01/08 14:09</b>
<b>22</b>	<b>6690</b>	<b>silicon near2 (oxynitr\$6 or oxy adj2 nitr\$6)</b>	<b>USPAT; US-PGPUB</b>	<b>2003/01/08 14:09</b>
<b>23</b>	<b>8</b>	<b>360/\$.ccls. and (silicon near2 (oxynitr\$6 or oxy adj2 nitr\$6))</b>	<b>USPAT; US-PGPUB</b>	<b>2003/01/08 14:10</b>